OCTAL BUFFER/DRIVER

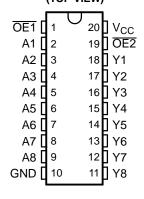
SN74LV541AT

www.ti.com

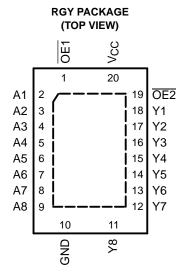
FEATURES

- Inputs Are TTL-Voltage Compatible
- 4.5-V to 5.5-V V_{CC} Operation
- Typical t_{nd} of 4 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce)
 <0.8 V at V_{CC} = 5 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 >2.3 V at V_{CC} = 5 V, T_A = 25°C
- Supports Mixed-Mode Voltage Operation on All Ports

DB, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



DESCRIPTION/ORDERING INFORMATION

The SN74LV541AT is designed for 4.5-V to 5.5-V V_{CC} operation. The inputs are TTL-voltage compatible, which allows them to be interfaced with bipolar outputs and 3.3-V devices. The device also can be used to translate from 3.3 V to 5 V.

ORDERING INFORMATION

T _A	PAC	CKAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Reel of 1000	SN74LV541ATRGYR	VV541
	SOIC - DW	Tube of 25	SN74LV541ATDW	- LV541AT
	SOIC - DW	Reel of 2000	SN74LV541ATDWR	LV341A1
	SOP - NS	Reel of 2000	SN74LV541ATNSR	74LV541AT
–40°C to 85°C	SSOP – DB	Reel of 2000	SN74LV541ATDBR	LV541AT
		Tube of 70	SN74LV541ATPW	
	TSSOP - PW	Reel of 2000	SN74LV541ATPWR	LV541AT
		Reel of 250	SN74LV541ATPWT	
	TVSOP - DGV	Reel of 2000	SN74LV541ATDGVR	LV541AT

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SCES573A-JUNE 2004-REVISED AUGUST 2005



DESCRIPTION/ORDERING INFORMATION (CONTINUED)

This device is ideal for driving bus lines or buffer memory address registers. It features inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

The 3-state control gate is a two-input AND gate with active-low inputs so that, if either output-enable (OE1 or OE2) input is high, all corresponding outputs are in the high-impedance state. The outputs provide noninverted data when they are not in the high-impedance state.

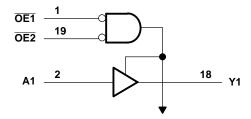
To ensure the high-impedance state during power up or power down, \overline{OE} shall be tied to VCC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

FUNCTION TABLE (EACH BUFFER/DRIVER)

	INPUTS							
OE1	OE2	Α	Y					
L	L	L	L					
L	L	Н	Н					
Н	Χ	X	Z					
X	Н	X	Z					

LOGIC DIAGRAM (POSITIVE LOGIC)



To Seven Other Channels

_



SN74LV541AT OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output in the	high-impedance or power-off state ⁽²⁾	-0.5	7	V
Vo	Output voltage range applied in the high o	or low state ⁽²⁾⁽³⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-20	mA
I _{OK}	Output clamp current	V _O < 0		– 50	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		±35	mA
	Continuous current through V _{CC} or GND			±70	mA
		DB package (4)		70	
		DGV package ⁽⁴⁾		92	
	Deal and the good from a day of	DW package ⁽⁴⁾		58	0000
θ_{JA}	Package thermal impedance	NS package ⁽⁴⁾		60	°C/W
		PW package ⁽⁴⁾		83	
		RGY package ⁽⁵⁾		37	
T _{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) This value is limited to 5.5 V maximum.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7
- (5) The package thermal impedance is calculated in accordance with JESD 51-5.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		4.5	5.5	V
V_{IH}	High-level input voltage	V _{CC} = 4.5 V to 5.5 V	2		V
V _{IL}	Low-level input voltage	V _{CC} = 4.5 V to 5.5 V		0.8	V
VI	Input voltage		0	5.5	V
Vo	Outrot valta aa	High or low state		V_{CC}	V
	Output voltage	3-state	0	5.5	V
I _{OH}	High-level output current	V _{CC} = 4.5 V to 5.5 V		-16	mA
I _{OL}	Low-level output current	V _{CC} = 4.5 V to 5.5 V		16	mA
Δt/Δν	Input transition rise or fall rate	V _{CC} = 4.5 V to 5.5 V		20	ns/V
T _A	Operating free-air temperature	·	-40	85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	т	A = 25°	С	T _A = -40°C to 85°C		UNIT	
			MIN	TYP	MAX	MIN	MAX		
V	$I_{OH} = -50 \mu A$	4.5 V	4.4	4.5		4.4		V	
V _{OH}	$I_{OH} = -16 \text{ mA}$	4.5 V	3.8			3.8		V	
V	$I_{OL} = 50 \mu A$	4.5 V		0	0.1).1		V	
V _{OL}	I _{OL} = 16 mA	4.5 V			0.55		0.55		
I _I	$V_I = 5.5 \text{ V or GND}$	0 to 5.5 V			±0.1		±1	μΑ	
l _{oz}	$V_O = V_{CC}$ or GND	5.5 V			±0.25		±2.5	μΑ	
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2		20	μΑ	
$\Delta I_{CC}^{(1)}$	One input at 3.4 V, Other inputs at V _{CC} or GND	5.5 V			1.35		1.5	mA	
I _{off}	V_I or $V_O = 0$ to 5.5 V	0			0.5		5	μΑ	
C _i	$V_I = V_{CC}$ or GND			2				pF	

⁽¹⁾ This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	LOAD CAPACITANCE	T,	λ = 25°C	;	T _A = -	UNIT	
	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	
t _{pd}	A	Y		2.6	5	6.9	1	8	
t _{en}	ŌĒ	Υ	$C_{L} = 15 pF$	3	8.3	11.3	1	13	ns
t _{dis}	ŌĒ	Υ		1.4	3.9	7.5	1	8	
t _{pd}	Α	Υ		4	5.5	7.9	1	9	
t _{en}	ŌĒ	Y	0 50 5	3.8	8.8	12.3	1	14	ns
t _{dis}	ŌĒ	Y	$C_L = 50 \text{ pF}$	2.1	9.4	11.9	1	13.5	
t _{sk(o)}						1		1	

Noise Characteristics⁽¹⁾

 $V_{\rm CC}$ = 5 V, $C_{\rm L}$ = 50 pF

	PARAMETER	Т	T _A = 25°C			
	PARAMETER	MIN	TYP	MAX	UNIT	
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		1.1	1.5	V	
$V_{OL(V)}$	Quiet output, minimum dynamic V _{OL}		-1.1	-1.5	V	
$V_{OH(V)}$	Quiet output, minimum dynamic V _{OH}		4		V	
$V_{IH(D)}$	High-level dynamic input voltage	2			V	
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V	

⁽¹⁾ Characteristics are for surface-mount packages only.

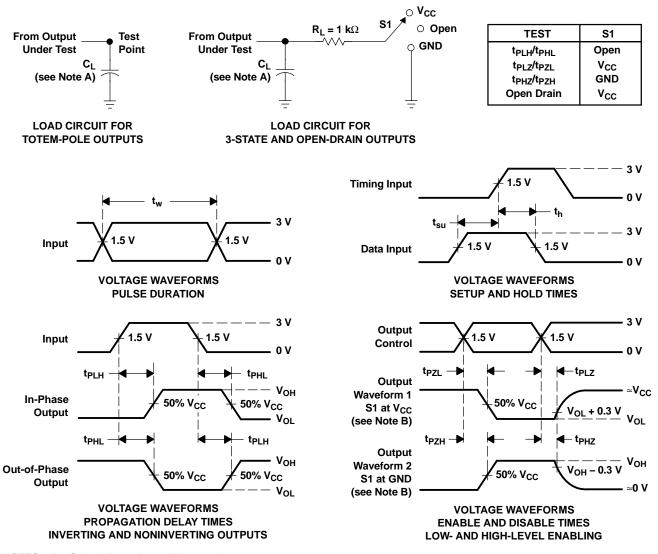
Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST C	TYP	UNIT		
C_{pd}	Power dissipation capacitance	Outputs enabled	$C_L = 50 \text{ pF},$	f = 10 MHz	8	pF



PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq 3$ ns, $t_f \leq 3$ ns.
 - D. The outputs are measured one at a time, with one input transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PHL} and t_{PLH} are the same as t_{pd}.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuits and Voltage Waveforms







PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74LV541ATDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDGVRE4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDGVRG4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATNSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATNSRE4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATNSRG4	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATPWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATPWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATPWT	ACTIVE	TSSOP	PW	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATPWTE4	ACTIVE	TSSOP	PW	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATPWTG4	ACTIVE	TSSOP	PW	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LV541ATRGYR	ACTIVE	QFN	RGY	20	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR



PACKAGE OPTION ADDENDUM

4-Jun-2007

Orderable Device	Status (1)	Package Type	Package Drawing		ckage Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74LV541ATRGYRG4	ACTIVE	QFN	RGY	20 1	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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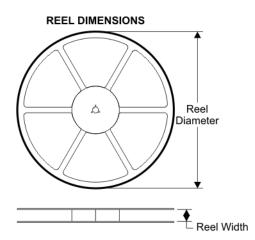
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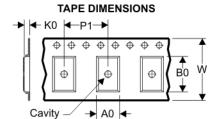




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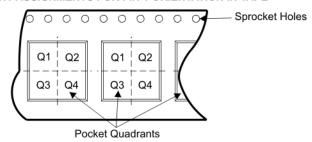
TAPE AND REEL BOX INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV541ATDBR	DB	20	SITE 41	330	16	8.2	7.5	2.5	12	16	Q1
SN74LV541ATDGVR	DGV	20	SITE 41	330	12	7.0	5.6	1.6	8	12	Q1
SN74LV541ATDWR	DW	20	SITE 41	330	24	10.8	13.0	2.7	12	24	Q1
SN74LV541ATNSR	NS	20	SITE 41	330	24	8.2	13.0	2.5	12	24	Q1
SN74LV541ATPWR	PW	20	SITE 41	330	16	6.95	7.1	1.6	8	16	Q1
SN74LV541ATRGYR	RGY	20	SITE 41	180	12	3.8	4.8	1.6	8	12	Q1





Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
SN74LV541ATDBR	DB	20	SITE 41	346.0	346.0	33.0
SN74LV541ATDGVR	DGV	20	SITE 41	346.0	346.0	29.0
SN74LV541ATDWR	DW	20	SITE 41	346.0	346.0	41.0
SN74LV541ATNSR	NS	20	SITE 41	346.0	346.0	41.0
SN74LV541ATPWR	PW	20	SITE 41	346.0	346.0	33.0
SN74LV541ATRGYR	RGY	20	SITE 41	190.0	212.7	31.75

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

DW (R-PDSO-G20)

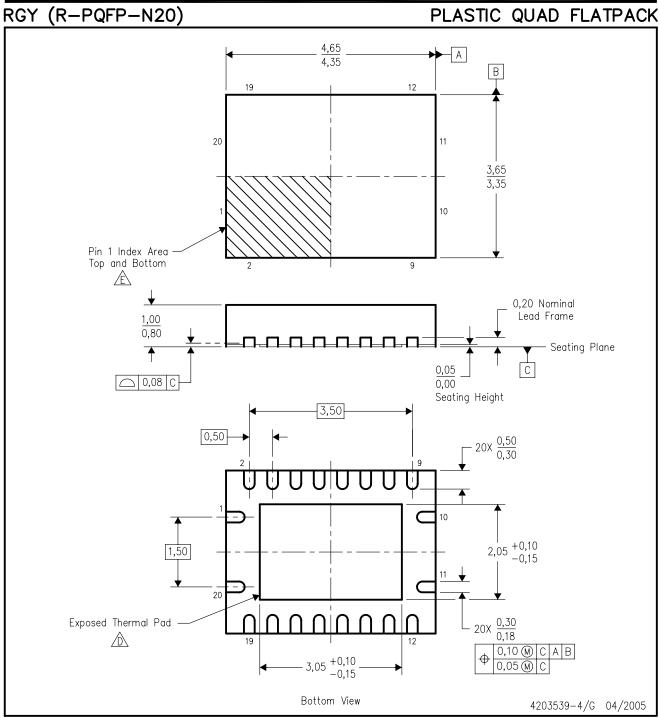
PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BC.

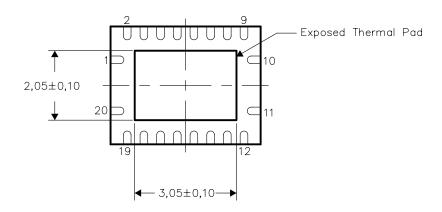


THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No—Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

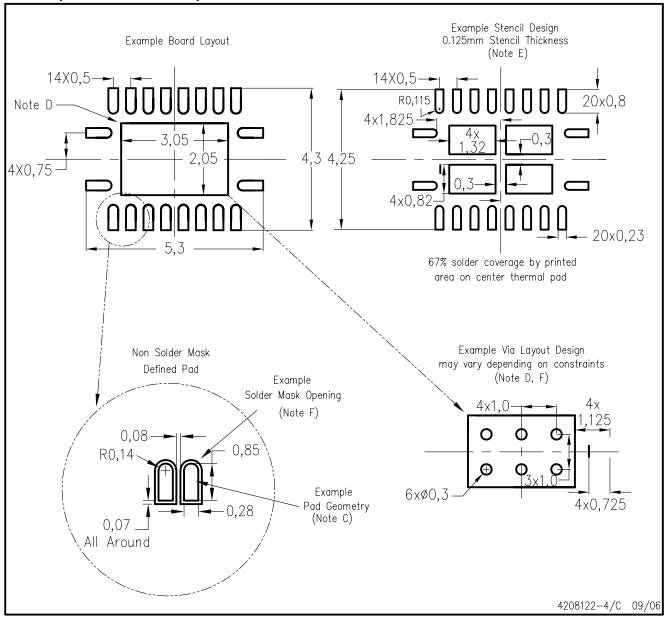


Bottom View

NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

RGY (R-PQFP-N20)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com https://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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